

Data sheet acquired from Harris Semiconductor SCHS073C – Revised October 2003

CMOS 8-Channel Data Selector

High-Voltage Types (20-Volt Rating)

■ CD4512B is an 8-channel data selector featuring a three-state output that can interface directly with, and drive, data lines of bus-oriented systems.

The CD4512B-series types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, MT, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

CD4512B Types

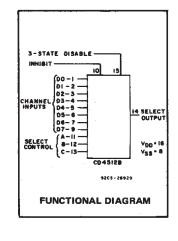
Features:

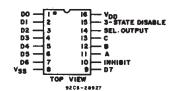
- **3**-state output
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- 5-V, 10-V, and 15-V parametric ratings
- Maximum input current of 1 μA at 18 V over full packagetemperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package-temperature range):

 Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Applications:

- Digital multiplexing
- Number-sequence generation
- Signal gating



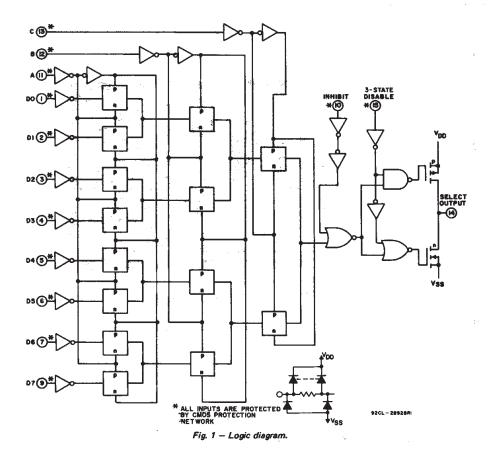


TERMINAL ASSIGNMENT

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

	LIN	AMUTO	
CHARACTERISTIC	MIN.	MAX.	UNITS
Supply-Voltage Range (For T _A = Full Package Temperature Range)	3	18	v



TRUTH TABLE

THOTH MALL										
SEL	COM	NT.	INH	3-STATE	SEL					
Α	В	С	114171	DISABLE	OUTPUT					
0	0	0	0	0	D0					
1	0	0	0	0	D1					
0	1	0	0	0	D2					
1	1	0	0	0	D3					
0	0	1	0	0	D4					
1	0	1	0	0	D 5					
0	1	1	0	0	D6					
1	1	1	0	0	D7					
х	x	X	1	0	0					
х	х	Ιx	х	1	High Z					

1 = High Level

0 = Low Level

X = Don't Care

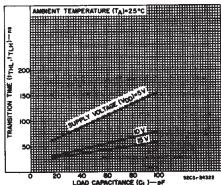


Fig. 2 — Typical transition time as a function of load capacitance.

CD4512B Types

MAXIMUM RATINGS, Absolute-Maximum Values:	
DC SUPPLY-VOLTAGE RANGE, (VDD)	
Voltages referenced to V _{SS} Terminal)	
INPUT VOLTAGE RANGE, ALL INPUTS0.5V to V _{DD} +0.5V	
DC INPUT CURRENT, ANY ONE INPUT	
POWER DISSIPATION PER PACKAGE (PD):	
For T _A = -55°C to +100°C	
For T _A = +100°C to +125°C	
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)	
OPERATING-TEMPERATURE RANGE (T _A)55°C to +125°C	
STORAGE TEMPERATURE RANGE (T _{stg})65°C to +150°C	
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max +265°C	

5 to	LOW (SIMK) CURRENT (I _{OL}) mA	A	WEN	EN	G.		(T 1 1 1 1 1 1 1 1 1		0 1100 1100	TA	GE	3				
	5 0		Ź		í		V2									

Fig. 3 — Typical output low (sink) current characteristics.

CHARAC- TERISTIC		DITIO	r :		LIMITS AT INDICATED TEMPERATURES (°C)								
	V _O (V)	V _{IN} (V)	V _{DD}	55	–40	+85	+125	Min.	+25 Typ.	Max.	S		
Quiescent	_	0,5	5	5	5	150	150	-	0.04	5			
Device		0,10	10	10	10	300	300	-	0.04	10	μΑ		
Current,	-	0,15	15	20	20	600	600	_	0.04	20	ļ		
- DD Max.	_	0,20	20	100	100	3000	3000		0.08	100	İ		
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-			
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	_			
OL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	_			
Output High	4.6	0,5	5	-0.64	0.61	-0.42	-0.36	-0.51	-1	_	m		
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	_			
Current, IOH Min.	9.5	0,10	10	1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-			
10H WIIII	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	_			
Output Voltage:	_	0,5	5		0.	.05	•	_	0	0.05			
Low-Level,	_	0,10	10		0.	.05		_	0	0.05			
VOL Max.	_	0,15	15		0.	.05		_	0	0.05	V		
Output	_	0,5	5		4.	.95		4.95	5	- <u>-</u>			
Voltage: High-Level,	_	0,10	10		9	95	9.95	10	1				
VOH Min.	_	0,15	15	W. L. C	14	95		14.95	15	- F			
Input Low	0.5,4.5		5		4	1.5		-		1.5			
Voltage	1,9	_	10			3				3			
V _{IL} Max.	1.5,13.5	_	15			4		1	-	4	v		
Input High	0.5,4.5	_	5			3.5		3.5	_	1	7.		
Voltage,	1,9		10		162	7		7		-			
V _{IH} Min.	1.5,13.5		15			11		11	-	* -			
Input Current IN Max.	-	0,18	18	±0.1	±0.1	‡1	±1		±10 ⁻⁵	±0.1	μ		
3-State Output Leakage Current IOUT Max.	0,18	0,18	18	±0.4	±0.4	±12	±12		±10 ⁻⁴	±0.4	μ		

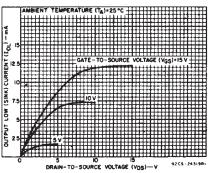


Fig. 4 — Minimum output low (sink) current characteristics.

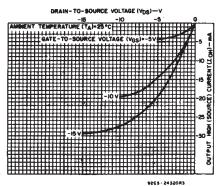


Fig. 5 — Typical output high (source) current characteristics.

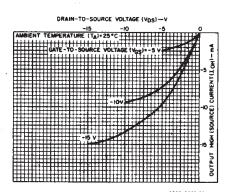


Fig. 6 — Minimum output high (source) current characteristics.

DYNAMIC ELECTRICAL CHARACTERISTICS at T_A = 25°C, Input t_r,t_f = 20 ns, C_L = 50 pF, R_L = 200 $k\Omega$

CHARACTERISTIC	TEST CONDITIONS	LIN	UNITS	
The second secon	V _{DD} (V)	Тур.	Max.	
Propagation Delay Time, tpHL, tpLH Inhibit to Output	5 10 15	140 70 50	280 140 100	
"A" Select to Output	5 10 15	200 85 60	400 170 120	ns
Data to Output	5 10 15	180 75 55	360 150 110	
3-State Disable Delay Time: [†] PZL, [†] PLZ, [†] PHZ, [†] PZH	5 10 15	60 30 20	120 60 40	ns
Transition Time, t _{THL} , t _{TLH}	5 10 15	100 50 40	200 100 80	ns
Input Capacitance, C _{IN} (Any Input)		5	7.5	pF

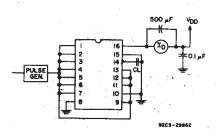


Fig. 9 - Dynamic power dissipation test circuit.

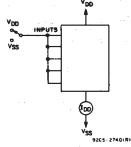


Fig. 10 - Quiescent device current test circuit.

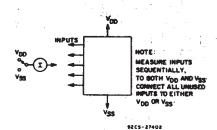


Fig. 11 - Input current test circuit.

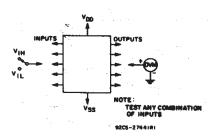
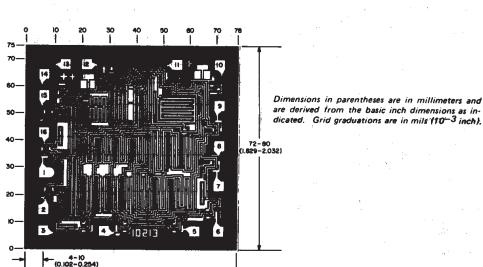


Fig. 12 - Input voltage test circuit.



Dimensions and pad layout for CD4512BH

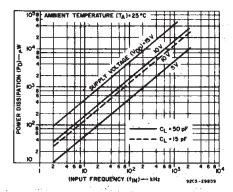


Fig. 7 — Typical dyanamic power dissipation as a function of frequency.

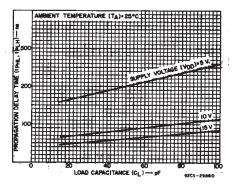


Fig. 8 — Typical propagation delay time as a function of load capacitance ("A" select to output).





i.com 28-Feb-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD4512BE	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD4512BF	ACTIVE	CDIP	J	16	1	None	Call TI	Level-NC-NC-NC
CD4512BF3A	ACTIVE	CDIP	J	16	1	None	Call TI	Level-NC-NC-NC
CD4512BM	ACTIVE	SOIC	D	16	40	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD4512BM96	ACTIVE	SOIC	D	16	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD4512BMT	ACTIVE	SOIC	D	16	250	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD4512BNSR	ACTIVE	SO	NS	16	2000	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD4512BPW	ACTIVE	TSSOP	PW	16	90	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM
CD4512BPWR	ACTIVE	TSSOP	PW	16	2000	Pb-Free (RoHS)	CU NIPDAU	Level-1-250C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

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14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AC.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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